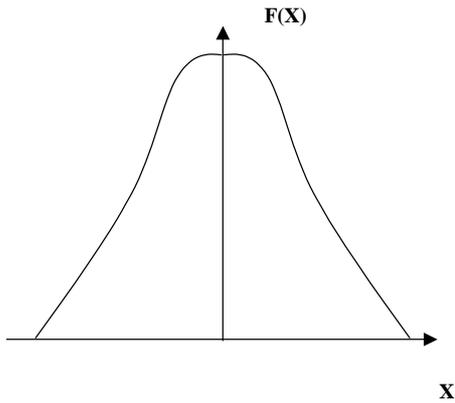




**Noise Tutorial**

**Fundamentals**

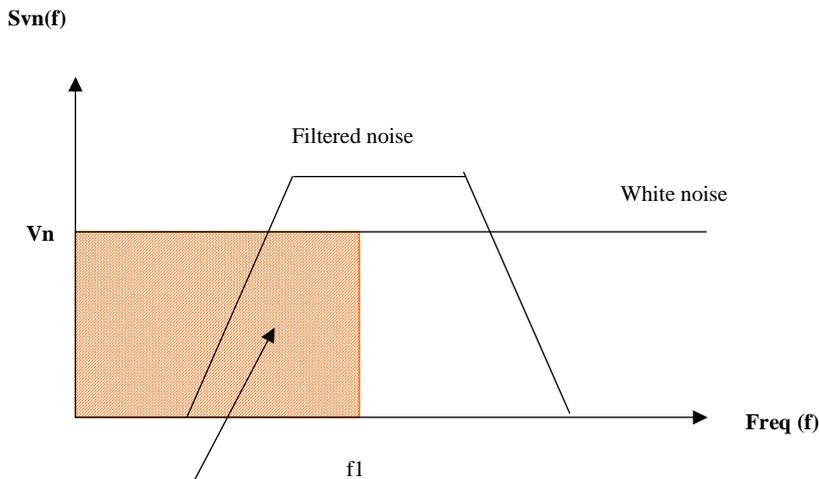
Objects capable of allowing the flow of electrical current will exhibit noise. This occurs as some electrons will have a random motion, causing fluctuating voltage and currents. As noise is random it can only be predicted by statistical means, usually with a Gaussian probability density function as shown below:-



As noise is random then it's mean value will be zero, hence we use **mean square** values, which are measurements of the dissipated noise power. The effective noise power of a source is measured in **root mean square** or **rms** values.

$$ie V_{n(rms)} = \sqrt{V_n^2}$$

**Noise power spectral density** – describes the noise content in a 1Hz bandwidth. Units are  $V^2/Hz$  and denotes as  $S_{vn}(f)$ . The graph below shows how  $S_{vn}(f)$  is defined.

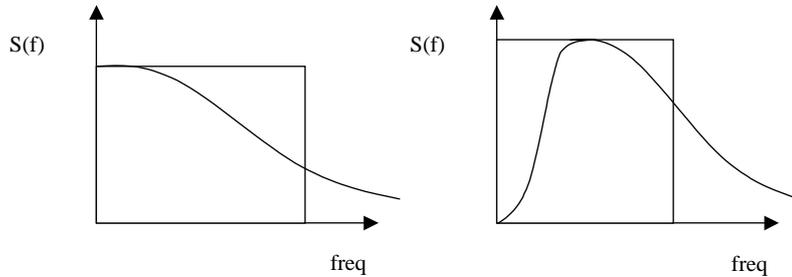


Total square noise  $v_n^2$  is found by integrating the spectral density function (ie the shaded area)

$$ie v_n^2 = \int S_{vn}(f).df = v_n^2.f1$$

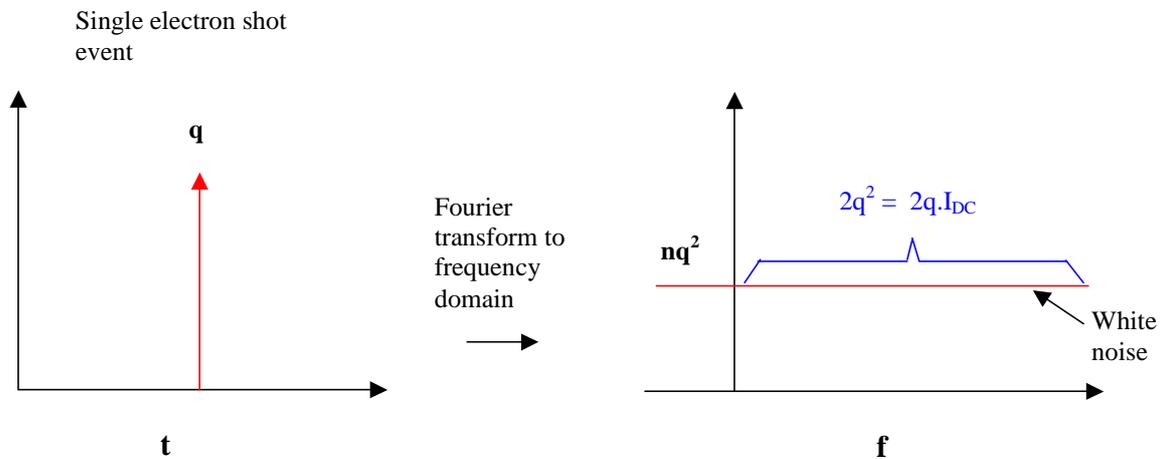


**Equivalent Noise Bandwidth (NBW)** - is defined as the frequency span of a noise power curve with an amplitude equal to the actual peak value, and with the same integrated area. In other words the NBW describes the bandwidth of a 'brick wall' system with the same noise power as the actual system ( $f_1$  is set such that the area of the 'brick wall' is ~ equal to the whole function). The graph below shows a couple of examples.



The main constituents of noise in a system, is due to Shot, Thermal, Burst, Avalanche and Flicker noise.

**Shot noise** – This noise is generated by current flowing across a P-N junction and is a function of the bias current and the electron charge. The impulse of charge  $q$  depicted as a single shot event in the time domain can be Fourier transformed into the frequency domain as a wideband noise ie



$$i_n^2 = 2nq^2 \Delta f = 2qI_{DC} \Delta f \quad I_{DC} = \text{bias current}; q = \text{electron charge}$$

**Thermal noise** – In any object with electrical resistance the thermal fluctuations of the electrons in the object will generate noise ie

$$v_n^2 = 4kTR \quad V^2 / \text{Hz} \quad \text{Where } k = \text{Boltzmann's constant } (1.38 \times 10^{-23} \text{ J/K})$$

The spectral density of thermal noise is flat with frequency and is known as white noise.

**Burst noise** – occurs in semiconductor devices, especially monolithic amplifiers and manifests as a noise crackle.



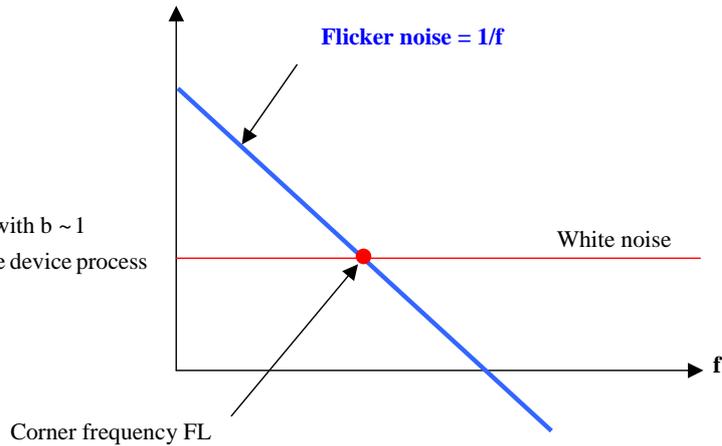
**Avalanche noise** – occurs in Zener diodes are reversed biased P-N junctions at breakdown. This noise is considerably larger than shot noise, so if zeners have to be used as part of a bias circuit then they need to be RF decoupled.

**Flicker noise** – This noise occurs in almost all electronic devices at low frequencies and takes the form of:-

$$i_f^2 = k \Delta f \left( \frac{I_a}{f_b} \right)$$

Where a is between 0.5 & 2, with b ~ 1  
k is variable depending on the device process

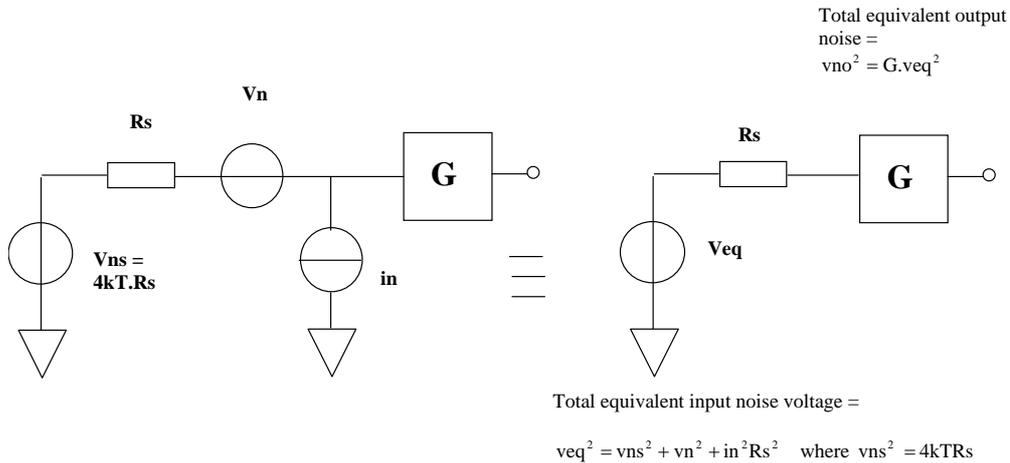
$$k = \frac{2q \cdot I_b \cdot FL}{f}$$



Flicker noise is usually defined by the corner frequency FL.

**Equivalent Noise Model**

When analysing a circuit we transform the many possible sources of noise (generating noise currents and voltages) to an equivalent noise source at the input of the circuit ie



**Noise Figure/Noise Factor**

The noise factor (F) of a device specifies how much additional noise the device will contribute to the noise already from the source.

The total equivalent input noise voltage =

$$v_{eq}^2 = v_{ns}^2 + v_n^2 + i_n^2 R_s^2 \quad \text{where } v_{ns}^2 = 4kTR_s$$

$$\text{Noise Factor} = \frac{v_{ns}^2 + v_n^2 + i_n^2 R_s^2}{v_{ns}^2} = 1 + \frac{v_n^2 + i_n^2 R_s^2}{v_{ns}^2}$$

$$v_{ns}^2 = 4kT.R_s \quad F = 1 + \frac{v_n^2 + i_n^2 R_s^2}{4kT.R_s}$$

**Noise factor (F)** is defined as the ratio of:

$$F = \frac{\text{Total equivalent input noise power}}{\text{Input noise power due to the source only}} \approx \frac{v_{eq}^2}{v_{ns}^2} = \frac{1 + v_n^2 + i_n^2 R_s^2}{v_{ns}^2}$$

Ideally  $F = 1$

**Noise figure (NF)** is the Noise factor converted to dB ie

$$\text{Noise Figure (NF)} = 10 \log_{10}(F) \text{dB}$$

Signal to Noise Ratio

$$\text{SNR}_{IN} = \frac{\text{Received signal power}}{\text{Received noise power}} = \frac{v_{sig}^2}{v_{ns}^2} \quad \text{Where } v_{ns}^2 = \text{receive noise from source}$$

$$\text{Similarly } \text{SNR}_{OUT} = \frac{\text{Output signal power}}{\text{Output noise power}} = \frac{G v_{sig}^2}{G v_{eq}^2} = \frac{v_{sig}^2}{v_{eq}^2}$$

$$\text{Thus, } \frac{\text{SNR}_{IN}}{\text{SNR}_{OUT}} = \frac{v_{eq}^2}{v_{ns}^2} = F$$